NSN 5961-00-933-7527

Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.185 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.360 inches
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.210 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
25.0 collector to base voltage/static/emitter open all transistor and 20.0 collector to emitter voltage/static/base open all transistor and 5.0
emitter to base voltage, static, collector open all transistor
Current Rating Per Characteristic:
100.00 microamperes all primaries all transistor
Power Rating Per Characteristic:
0.5 watts small-signal input power, common-collector absolute all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
All transistor junction pattern arrangement: pnp
Terminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0